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Power MOSFET -10 Amps, -20 Volts

P-Channel SOT-223

Features

- Low R_{DS(on)}
- Logic Level Gate Drive
- Diode Exhibits High Speed, Soft Recovery
- Avalanche Energy Specified
- NVF Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable*
- These Devices are Pb-Free and are RoHS Compliant

Typical Applications

• Power Management in Portables and Battery–Powered Products, i.e.: Cellular and Cordless Telephones and PCMCIA Cards

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

Rating	Symbol	Value	Unit		
Drain-to-Source Voltage	V_{DSS}	-20	Vdc		
Gate-to-Source Voltage	V _{GS}	±8.0	Vdc		
Drain Current (Note 1) – Continuous @ T _A = 25°C – Continuous @ T _A = 70°C – Single Pulse (t _p = 10 μs)	I _D I _D I _{DM}	-10 -8.4 -35	Adc Apk		
Total Power Dissipation @ T _A = 25°C	PD	8.3	W		
Operating and Storage Temperature Range	T _J , T _{stg}	−55 to +150	°C		
$ \begin{array}{l} \mbox{Single Pulse Drain-to-Source Avalanche} \\ \mbox{Energy} - \mbox{Starting } T_J = 25^\circ C \\ (V_{DD} = -20 \mbox{ Vdc}, V_{GS} = -5.0 \mbox{ Vdc}, \\ I_{L(pk)} = -10 \mbox{ A}, \mbox{L} = 3.0 \mbox{ mH}, \mbox{ R}_G = 25\Omega) \end{array} $	E _{AS}	150	mJ		
Thermal Resistance – Junction to Lead (Note 1) – Junction to Ambient (Note 2) – Junction to Ambient (Note 3)	$f{R}_{ heta JL} \ f{R}_{ heta JA} \ f{R}_{ heta JA}$	15 71.4 160	°C/W		
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	ΤL	260	°C		

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Steady State.

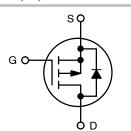
- 2. When surface mounted to an FR4 board using 1" pad size, (Cu. Area 1.127 sq in), Steady State.
- When surface mounted to an FR4 board using minimum recommended pad size, (Cu. Area 0.412 sq in), Steady State.



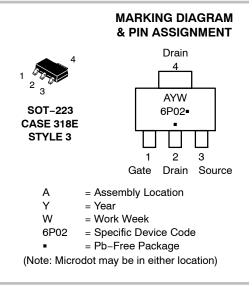
ON Semiconductor®

http://onsemi.com

–10 AMPERES –20 VOLTS R_{DS(on)} = 44 mΩ (Typ.)



P-Channel MOSFET



ORDERING INFORMATION

Device	Package	Shipping [†]
NTF6P02T3G	SOT-223 (Pb-Free)	4000 / Tape & Reel
NVF6P02T3G*	SOT-223 (Pb-Free)	4000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

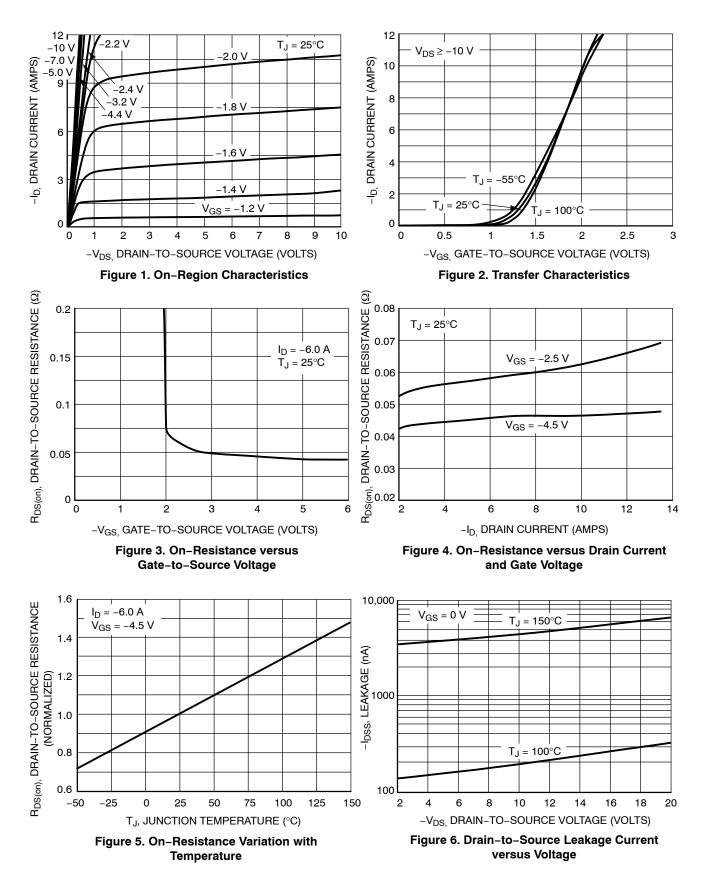
ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise noted)

Characteristic			Min	Тур	Мах	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage (Note 4) (V _{GS} = 0 Vdc, I _D = -250 μAdc) Temperature Coefficient (Positive)			-20 -	-25 -11		Vdc mV/°C
Zero Gate Voltage Drain Current $(V_{DS} = -20 \text{ Vdc}, V_{GS} = 0 \text{ Vdc})$ $(V_{DS} = -20 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, T_J = 0 \text{ Vdc}$	I _{DSS}	-		-1.0 -10	μAdc	
$ Gate-Body Leakage Current \\ (V_{GS} = \pm 8.0 \text{ Vdc}, V_{DS} = 0 \text{ Vdc}) $			-	-	± 100	nAdc
ON CHARACTERISTICS (Note 4)				•		•
$\label{eq:second} \begin{array}{l} \mbox{Gate Threshold Voltage (Note 4)} \\ (V_{DS} = V_{GS}, I_{D} = -250 \ \mu \mbox{Adc}) \\ \mbox{Threshold Temperature Coefficient (Negative)} \end{array}$			-0.4	-0.7 2.6	-1.0 _	Vdc mV/°C
$\begin{array}{l} \mbox{Static Drain-to-Source On-Resistance (Note 4)} \\ (V_{GS} = -4.5 \mbox{ Vdc}, I_D = -6.0 \mbox{ Adc}) \\ (V_{GS} = -2.5 \mbox{ Vdc}, I_D = -4.0 \mbox{ Adc}) \\ (V_{GS} = -2.5 \mbox{ Vdc}, I_D = -3.0 \mbox{ Adc}) \end{array}$				44 57 57	50 70 -	mΩ
Forward Transconductance (Note 4) $(V_{DS} = -10 \text{ Vdc}, I_D = -6.0 \text{ Adc})$	9 _{fs}	-	12	-	Mhos	
DYNAMIC CHARACTERISTICS						•
Input Capacitance	$(V_{DS} = -16 \text{ Vdc}, V_{GS} = 0 \text{ V},$	C _{iss}	-	900	1200	pF
Output Capacitance	f = 1.0 MHz)	C _{oss}	-	350	500	
Transfer Capacitance		C _{rss}	-	90	150	1
Input Capacitance	$(V_{DS} = -10 \text{ Vdc}, V_{GS} = 0 \text{ V},$	C _{iss}	-	940	-	pF
Output Capacitance	f = 1.0 MHz)	C _{oss}	-	410	-	
Transfer Capacitance		C _{rss}	-	110	-	1
SWITCHING CHARACTERISTICS	(Note 5)					
Turn-On Delay Time	$(V_{DD} = -5.0 \text{ Vdc}, I_D = -1.0 \text{ Adc},$	t _{d(on)}	-	7.0	12	ns
Rise Time	$V_{GS} = -4.5 \text{ Vdc},$ $R_G = 6.0 \Omega)$	t _r	-	25	45	
Turn-Off Delay Time	<u> </u>	t _{d(off)}	-	75	125	-
Fall Time		t _f	-	50	85	
Turn-On Delay Time	$(V_{DD} = -16 \text{ Vdc}, I_D = -6.0 \text{ Adc},$	t _{d(on)}	_	8.0	-	ns
Rise Time	$V_{GS} = -4.5 \text{ Vdc},$ $R_G = 2.5 \Omega)$	t _r	-	30	-	-
Turn-Off Delay Time	~ <i>,</i>	t _{d(off)}	-	60	-	
Fall Time		t _f	-	60	-	1
Gate Charge	$(V_{DS} = -16 \text{ Vdc}, I_D = -6.0 \text{ Adc}, V_{GS} = -4.5 \text{ Vdc}) \text{ (Note 4)}$	Q _T	-	15	20	nC
		Q _{gs}	-	1.7	-	1
		Q _{gd}	-	6.0	_	1

Forward On-Voltage		V _{SD}	_ _ _	-0.82 -0.74 -0.68	-1.2 - -	Vdc
Reverse Recovery Time $(I_{S} = -3.0 \text{ Adc}, V_{GS} = 0 \text{ Vdc},$	t _{rr}	-	42	-	ns	
	dI _S /dt = 100 A/µs) (Note 4)	ta	-	17	-	
		t _b	_	25	-	1
Reverse Recovery Stored Charge		Q _{RR}	-	0.036	-	μC

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.
Switching characteristics are independent of operating junction temperatures.

TYPICAL ELECTRICAL CHARACTERISTICS



TYPICAL ELECTRICAL CHARACTERISTICS

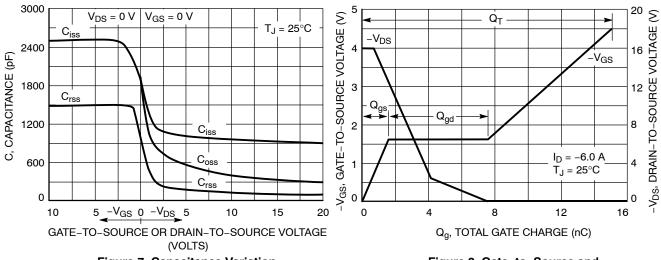


Figure 7. Capacitance Variation

Figure 8. Gate-to-Source and Drain-to-Source Voltage versus Total Charge

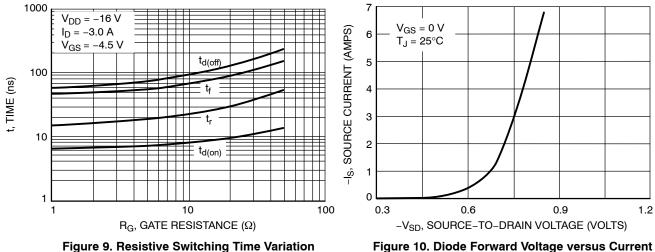


Figure 9. Resistive Switching Time Variation versus Gate Resistance

TYPICAL ELECTRICAL CHARACTERISTICS

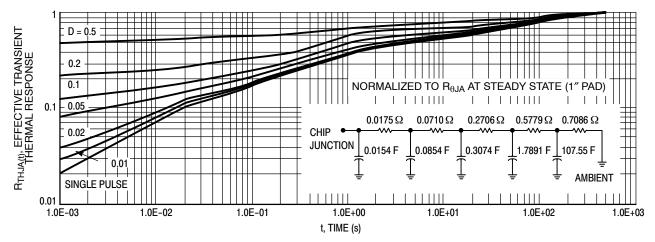
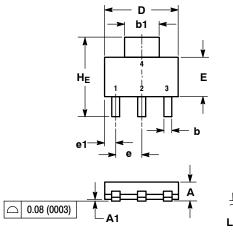
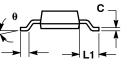


Figure 11. FET Thermal Response

PACKAGE DIMENSIONS

SOT-223 (TO-261) CASE 318E-04 ISSUE N





NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: INCH.

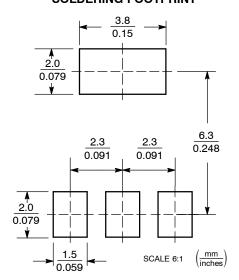
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
С	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
Е	3.30	3.50	3.70	0.130	0.138	0.145
е	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
L	0.20			0.008		
L1	1.50	1.75	2.00	0.060	0.069	0.078
HE	6.70	7.00	7.30	0.264	0.276	0.287
θ	0°	-	10°	0°	-	10°

SOLDERING FOOTPRINT*

STYLE 3: PIN 1. GATE

2. DRAIN

3. SOURCE 4. DRAIN



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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